VS-VSKJS409/150

Vishay Semiconductors





www.vishay.com

AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS			
I _{F(AV)} 400 A			
V _R	150 V		
Package	AAP Gen 7 (TO-240AA)		
Circuit configuration	Two diodes common anode		

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- Low thermal resistance



- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKJS409/150 Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters,

freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	400	А	
V _{RRM}		150	V	
I _{FSM}	t _p = 5 μs sine	20 000	А	
V _F	200 A _{pk} , T _J = 125 °C	0.85	V	
TJ	Range	-55 to +175	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL VS-VSKJS409/150		UNITS	
Maximum DC reverse voltage	V _R	150	V	
Maximum working peak reverse voltage	V _{RWM}	150	v	

RoHS COMPLIANT

Revision: 03-May-17

Document Number: 93106

1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	OL TEST CONDITIONS VAL		VALUES	UNITS
Maximum average	per module		50 % duty cycle at T _C = 105 °C, rectangular waveform		400	
forward current	per leg	I _{F(AV)}			200	
Maximum peak one cycle			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	20 000	A
non-repetitive surge curre	nt	IFSM	1 310	rated V _{RRM} applied	2300	
Non-repetitive avalanche	energy	E_{AS} T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH		15	mJ	
Repetitive avalanche curre	ent	I _{AR}	$\frac{1}{3} \qquad \begin{array}{l} \text{Current decaying linearly to zero in 1 } \mu s \\ \text{Frequency limited by } T_J \text{ maximum } V_A = 1.5 \text{ x } V_B \text{ typical} \end{array} \qquad 1$		1	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	L TEST CONDITIONS VA		VALUES	UNITS
	V _{FM}	200 A	T _J = 25 °C	1.03	v
		400 A		1.33	
Maximum forward voltage drop		200 A	- T _J = 125 °C	0.85	
		400 A		1.13	
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current		T _J = 125 °C		85	ША
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		6000	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	R _{thJC} DC operation		°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	
Approximate weight				75	g
				2.7	oz.
Mounting torque ± 10 % -	to heatsink		A mounting compound is recommended and the torque	4	- Nm
	busbar		should be rechecked after a period of 3 h to allow for the spread of the compound.	3	
Case style			JEDEC®	TO-240AA co	ompatible

Revision: 03-May-17 2 Document Number: 93106 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



VS-VSKJS409/150

Vishay Semiconductors

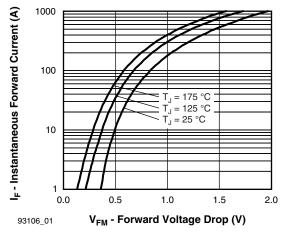
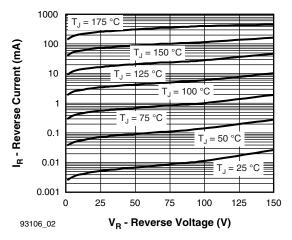
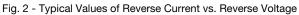


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





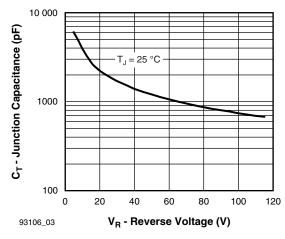
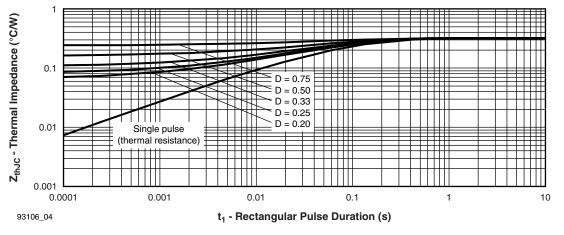
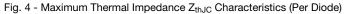


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



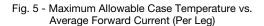


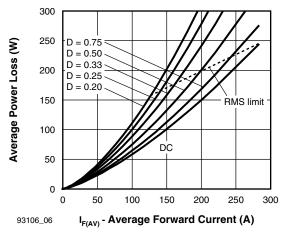
 Revision: 03-May-17
 3
 Document Number: 93106

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



180 Allowable Case Temperature (°C) 160 140 120 DC 100 80 60 Square wave (D = 0.50)40 80 % rated $\rm V_R$ applied 20 See note (1) 0 0 100 200 300 400 500 I_{F(AV)} - Average Forward Current (A) 93106 05





VS-VSKJS409/150

Vishay Semiconductors

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

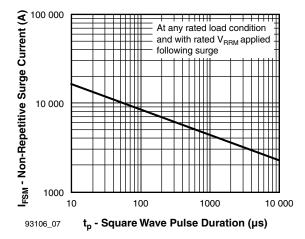


Fig. 7 - Maximum Non-Repetitive Surge Current

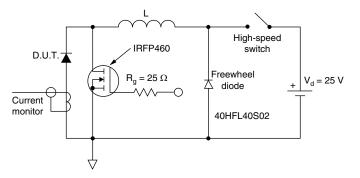


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 03-May-17

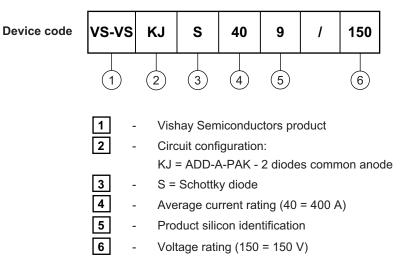
4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

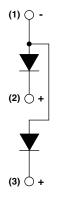
Vishay Semiconductors



ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

Vishay Semiconductors



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1